



# HiPerFET™ Power MOSFETs ISOPLUS247™

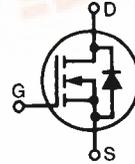
IXFR 26N50Q  
IXFR 24N50Q

$V_{DSS}$	$I_{D25}$	$R_{DS(on)}$
500 V	24 A	0.20 $\Omega$
500 V	22 A	0.23 $\Omega$

(Electrically Isolated Back Surface)

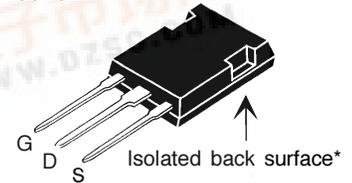
$t_{rr} \leq 250$  ns

N-Channel Enhancement Mode  
High dV/dt, Low  $t_{rr}$ , HDMOS™ Family



Symbol	Test Conditions	Maximum Ratings	
$V_{DSS}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$	500	V
$V_{DGR}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ ; $R_{GS} = 1$ M $\Omega$	500	V
$V_{GS}$	Continuous	$\pm 20$	V
$V_{GSM}$	Transient	$\pm 30$	V
$I_{D25}$	$T_C = 25^\circ\text{C}$	26N50Q: 24 24N50Q: 22	A
$I_{DM}$	$T_C = 25^\circ\text{C}$ , Pulse width limited by $T_{JM}$	26N50Q: 104 24N50Q: 96	A
$I_{AR}$	$T_C = 25^\circ\text{C}$	26N50Q: 26 24N50Q: 24	A
$E_{AR}$	$T_C = 25^\circ\text{C}$	30	mJ
$E_{AS}$	$T_C = 25^\circ\text{C}$	1.5	J
$dv/dt$	$I_S \leq I_{DM}$ , $di/dt \leq 100$ A/ $\mu\text{s}$ , $V_{DD} \leq V_{DSS}$ $T_J \leq 150^\circ\text{C}$ , $R_G = 2$ $\Omega$	5	V/ns
$P_D$	$T_C = 25^\circ\text{C}$	250	W
$T_J$		-55 ... +150	$^\circ\text{C}$
$T_{JM}$		150	$^\circ\text{C}$
$T_{stg}$		-55 ... +150	$^\circ\text{C}$
$T_L$	1.6 mm (0.062 in.) from case for 10 s	300	$^\circ\text{C}$
$V_{ISOL}$	50/60 Hz, RMS $t = 1$ minute leads-to-tab	2500	V~
Weight		5	g

ISOPLUS247™  
E153432



G = Gate      D = Drain  
S = Source

\* Patent pending

### Features

- Silicon chip on Direct-Copper-Bond substrate
  - High power dissipation
  - Isolated mounting surface
  - 2500V electrical isolation
- Low drain to tab capacitance (<35pF)
- Low  $R_{DS(on)}$  HDMOS™ process
- Rugged polysilicon gate cell structure
- Unclamped Inductive Switching (UIS) rated
- Fast intrinsic Rectifier

### Applications

- DC-DC converters
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- AC motor control

### Advantages

- Easy assembly: no screws, or isolation foils required
- Space savings
- High power density
- Low collector capacitance to ground (low EMI)

Symbol	Test Conditions	Characteristic Values ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$V_{DSS}$	$V_{GS} = 0$ V, $I_D = 250$ $\mu\text{A}$	500		V
$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 4$ mA	2.5		V
$I_{GSS}$	$V_{GS} = \pm 20$ V <sub>DC</sub> , $V_{DS} = 0$			$\pm 100$ nA
$I_{DSS}$	$V_{DS} = 0.8$ $V_{DSS}$			25 $\mu\text{A}$
	$V_{GS} = 0$ V			1 mA
$R_{DS(on)}$	$V_{GS} = 10$ V, $I_D = I_T$ Notes 1 & 2			0.20 $\Omega$
				0.23 $\Omega$

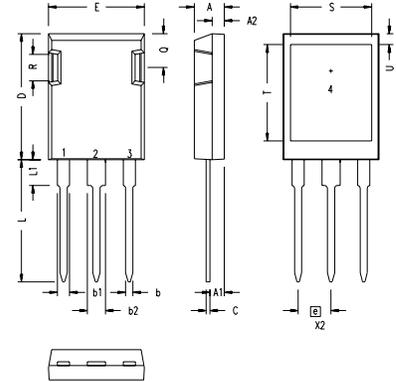


Symbol	Test Conditions	Characteristic Values ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)	Characteristic Values		
			min.	typ.	max.
$g_{fs}$	$V_{DS} = 15\text{ V}; I_D = I_T$ Note 1		14	24	S
$C_{iss}$	$V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$			3900	pF
$C_{oss}$				500	pF
$C_{rss}$				130	pF
$t_{d(on)}$	$V_{GS} = 10\text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = I_T$ $R_G = 1\ \Omega$ (External),			28	ns
$t_r$				30	ns
$t_{d(off)}$				55	ns
$t_f$				16	ns
$Q_{g(on)}$	$V_{GS} = 10\text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = I_T$			95	nC
$Q_{gs}$				27	nC
$Q_{gd}$				40	nC
$R_{thJC}$				0.50	K/W
$R_{thCK}$			0.15		K/W

Symbol	Test Conditions	Characteristic Values ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)	Characteristic Values				
			min.	typ.	max.		
$I_s$	$V_{GS} = 0\text{ V}$			26	A		
$I_{SM}$	Repetitive; pulse width limited by $T_{JM}$			104	A		
$V_{SD}$	$I_F = I_s, V_{GS} = 0\text{ V}$ , Note 1			1.3	V		
$t_{rr}$	$I_F = I_s, -di/dt = 100\text{ A}/\mu\text{s}$ $V_R = 100\text{ V}$	$T_J = 25^\circ\text{C}$		250	ns		
$Q_{RM}$				$T_J = 25^\circ\text{C}$	0.85	1.5	$\mu\text{C}$
$I_{RM}$				$T_J = 25^\circ\text{C}$	8		A

- Note: 1. Pulse test,  $t \leq 300\ \mu\text{s}$ , duty cycle  $d \leq 2\%$   
 2.  $I_T$  test current: IXFR26N50Q  $I_T = 13\text{ A}$   
 IXFR24N50Q  $I_T = 12\text{ A}$   
 3. See IXFH26N50Q data sheet for characteristic curves.

### ISOPLUS247 OUTLINE



SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.190	.205	4.83	5.21
A1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
b	.045	.055	1.14	1.40
b1	.075	.084	1.91	2.13
b2	.115	.123	2.92	3.12
C	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
E	.620	.635	15.75	16.13
e	.215 BSC		5.45 BSC	
L	.780	.800	19.81	20.32
L1	.150	.170	3.81	4.32
Q	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83
S	.520	.540	13.21	13.72
T	.620	.640	15.75	16.26
U	.065	.080	1.65	2.03

- 1 - GATE
- 2 - DRAIN (COLLECTOR)
- 3 - SOURCE (EMITTER)
- 4 - NO CONNECTION

NOTE: This drawing will meet all dimensions requirement of JEDEC outline TO-247AD except screw hole.